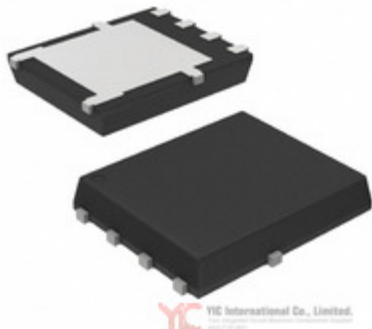

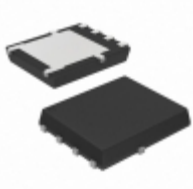
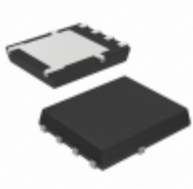
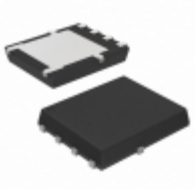
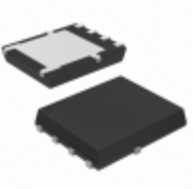
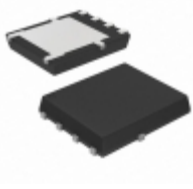
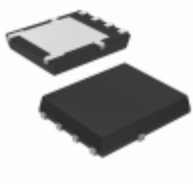
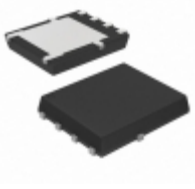
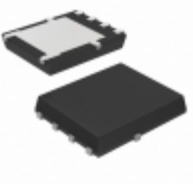
	<p>NVMFS5C612NLT1G</p>
	<p>Hersteller-Teilenummer: NVMFS5C612NLT1G</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 60V 36A SO8FL</p>
	<p>Datenblätter:  NVMFS5C612NLT1G.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	NVMFS5C612NLT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 36A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	2V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	-
Rds On (Max) @ Id, Vgs	1.5 mOhm @ 50A, 10V
Verlustleistung (max)	3.8W (Ta), 167W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	6660pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	91nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	36A (Ta), 235A (Tc)

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Sie können auch interessiert

<p>sein:</p>  <p>NVMFS5C612NLAFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 38A 250A 5DFN</p>	 <p>NVMFS5C612NLWFAFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 38A 250A 5DFN</p>	 <p>NVMFS5C604NLWFT1G ON Semiconductor MOSFET N-CH 60V 40A SO8FL</p>	 <p>NVMFS5C612NLAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 38A 250A 5DFN</p>
 <p>NVMFS5C604NLWFT3G ON Semiconductor MOSFET N-CH 60V 40A SO8FL</p>	 <p>NVMFS5C612NLT3G ON Semiconductor MOSFET N-CH 60V 36A SO8FL</p>	 <p>NVMFS5C604NLWFAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 287A 5DFN</p>	 <p>NVMFS5C612NLWFT1G ON Semiconductor MOSFET N-CH 60V 36A SO8FL</p>

Verwandtes Hot-Keyword

Mehr

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NVMFS5C612NLT1G Electronic	NVMFS5C612NLT1G-Komponenten	NVMFS5C612NLT1G-Verteiler	NVMFS5C612NLT1G-Bild	NVMFS5C612NLT1G-Teil
NVMFS5C612NLT1G Preis	NVMFS5C612NLT1G Hersteller	NVMFS5C612NLT1G Bild	NVMFS5C612NLT1G Aktie	NVMFS5C612NLT1G Inventar
NVMFS5C612NLT1G Neu	NVMFS5C612NLT1G Original	NVMFS5C612NLT1G garantiert	NVMFS5C612NLT1G RFQ	NVMFS5C612NLT1G Online bestellen

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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